

MJ11012G

MJ11012G Information

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Part Number	MJ11012G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single
Description	TRANS NPN DARL 60V 30A TO-3
Package	ТО-204АА, ТО-3
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

For Reference Only

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



MJ11012G Specifications

Manufacturer Part Number	MJ11012G	
Manufacturer	ON Semiconductor	
Category	Discrete Semiconductor Products	
	Transistors - Bipolar (BJT) - Single	
Package	ТО-204АА, ТО-3	
Series	-	
Transistor Type	NPN - Darlington	
Current - Collector (Ic) (Max)	30A	
Voltage - Collector Emitter Breakdown (Max)	60V	
Vce Saturation (Max) @ Ib, Ic	4V @ 300mA, 30A	
Current - Collector Cutoff (Max)	1mA	
DC Current Gain (hFE) (Min) @ Ic, Vce	1000 @ 20A, 5V	
Power - Max	200W	
Frequency - Transition	4MHz	
Operating Temperature	-55°C ~ 200°C (TJ)	
Mounting Type	Through Hole	
Package / Case	ТО-204АА, ТО-3	
Supplier Device Package	TO-3	
	Report errors?	

MJ11012G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE EUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

MJ11012G Payment Methods



MJ11012G Shipping Methods



If you have any question about MJ11012G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com